TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7WG02FU,TC7WG02FK

#### **Dual 2-Input NOR Gate**

#### **Features**

• High-level output current:  $I_{OH}/I_{OL} = \pm 8 \text{ mA (min)}$ 

at  $V_{CC} = 3 V$ 

• High-speed operation: t<sub>pd</sub> = 2.8 ns (typ.)

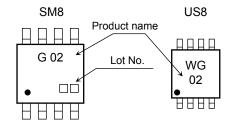
at  $V_{CC} = 3.3 \text{ V}, 15 \text{pF}$ 

• Operating voltage range: V<sub>CC</sub> = 0.9~3.6 V

• 5.5-V tolerant inputs

• 3.6-V power down protection outputs

#### Marking



# TC7WG02FU SSOP8-P-0.65 TC7WG02FK SSOP8-P-0.50A

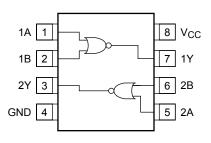
Weight

SSOP8-P-0.65 : 0.02 g (typ.) SSOP8-P-0.50A : 0.01 g (typ.)

#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Value	Unit	
Power supply voltage	V <sub>CC</sub>	-0.5~4.6	V	
DC input voltage	V <sub>IN</sub>	-0.5~7.0	V	
DC output voltage	V	-0.5~4.6 (Note 1)	V	
	Vout	-0.5~V <sub>CC</sub> + 0.5 (Note 2)	V	
Input diode current	ΙIK	-20	mA	
Output diode current	lok	-20 (Note 3)	mA	
DC output current	lout	±25	mA	
DC V <sub>CC</sub> / ground current	Icc	±50	mA	
Power dissipation	PD	300 (SM8) 200 (US8)	mW	
Storage temperature	T <sub>stg</sub>	-65~150	°C	

### Pin Assignment (top view)



Note:

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1:  $V_{CC} = 0 V$ 

Note 2: High or Low State. IOUT absolute maximum rating must be observed.

Note 3: V<sub>OUT</sub> < GND

# **IEC Logic Symbol**



#### **Truth Table**

Inp	Outputs			
А	В	Υ		
L	L	Н		
L	Н	L		
Н	L	L		
Н	Н	L		

# **Operating Ranges**

Characteristics	Symbol	Value	Unit	
Power supply voltage	V <sub>CC</sub>	0.9~3.6	V	
Input voltage	V <sub>IN</sub>	0~5.5	V	
Output voltage	\/a	0~3.6 (Note 4)	V	
	V <sub>OUT</sub>	0~V <sub>CC</sub> (Note 5)	v	
Output Current		±8.0 (Note 6)		
		±4.0 (Note 7)		
		±3.0 (Note 8)		
	I <sub>OH</sub> /I <sub>OL</sub>	±1.7 (Note 9)	mA	
		±0.3 (Note 10)		
		±0.02 (Note 11)	1	
Operating temperature	T <sub>opr</sub>	-40~85	°C	
Input rise and fall time	dt/dV	0~10 (Note 12)	ns/V	

Note 4:  $V_{CC} = 0V$ 

Note 5: High or Low state.

Note 6:  $V_{CC} = 3.0 \sim 3.6 \text{ V}$ 

Note 7:  $V_{CC} = 2.3 \sim 2.7 \text{ V}$ 

Note 8:  $V_{CC} = 1.65 \sim 1.95 \text{ V}$ 

Note 9:  $V_{CC} = 1.4 \sim 1.6 \text{ V}$ 

Note 10: V<sub>CC</sub> = 1.1~1.3 V

Note 11:  $V_{CC} = 0.9 \text{ V}$ 

Note 12:  $V_{IN} = 0.8 \sim 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$ 

# **Electrical Characteristics**

#### **DC Characteristics**

Characteristics Symbol			Symbol Test Condition			Ta = 25°C			Ta = -40~85°C		
		Symbol			V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Unit
					0.9	V <sub>CC</sub>	_	_	V <sub>CC</sub>	_	
Higl		V <sub>IH</sub>	_		1.1~1.3	V <sub>CC</sub> × 0.7	_	_	V <sub>CC</sub> × 0.7	_	
	High level				1.4~1.6	V <sub>CC</sub> × 0.65		_	V <sub>CC</sub> × 0.65		
					1.65~ 1.95	V <sub>CC</sub> × 0.65	_	_	V <sub>CC</sub> × 0.65	_	
					2.3~2.7	1.7	_	_	1.7	_	
Input voltage					3.0~3.6	2.0	_		2.0		V
put voltago					0.9	_	_	GND	_	GND	•
					1.1~1.3	_		V <sub>CC</sub> × 0.3	_	$\begin{array}{c} V_{CC} \\ \times \ 0.3 \end{array}$	
	Low level	V <sub>IL</sub>	_		1.4~1.6		١	V <sub>CC</sub> × 0.35	ı	V <sub>CC</sub> × 0.35	
					1.65~ 1.95	_		V <sub>CC</sub> × 0.35		V <sub>CC</sub> × 0.35	
					2.3~2.7	_		0.7	_	0.7	
					3.0~3.6	_	_	0.8		8.0	
				I <sub>OH</sub> =-0.02 mA	0.9	0.75		_	0.75		V
		Vон	$V_{IN} = V_{IL}$	$I_{OH} = -0.3 \text{ mA}$	1.1~1.3	V <sub>CC</sub> × 0.75		_	V <sub>CC</sub> × 0.75		
	High level			I <sub>OH</sub> = -1.7 mA	1.4~1.6	V <sub>CC</sub> × 0.75	_	_	V <sub>CC</sub> × 0.75	_	
				I <sub>OH</sub> = -3.0 mA	1.65~ 1.95	V <sub>CC</sub> -0.45	_	_	V <sub>CC</sub> -0.45		
				$I_{OH} = -4.0 \text{ mA}$	2.3~2.7	2.0			2.0		
Output valtage				$I_{OH} = -8.0 \text{ mA}$	3.0~3.6	2.48		_	2.48		
Output voltage				$I_{OL} = 0.02 \text{ mA}$	0.9	_	_	0.1	_	0.1	
			V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 0.3 mA	1.1~1.3	_	_	V <sub>CC</sub> × 0.25	_	V <sub>CC</sub> × 0.25	
	Low level	V <sub>OL</sub>		I <sub>OL</sub> = 1.7 mA	1.4~1.6	_	_	V <sub>CC</sub> × 0.25	_	V <sub>CC</sub> × 0.25	
				I <sub>OL</sub> = 3.0 mA	1.65~ 1.95	_	_	0.45	_	0.45	
				I <sub>OL</sub> = 4.0 mA	2.3~2.7	_	_	0.4	_	0.4	
				I <sub>OL</sub> = 8.0 mA	3.0~3.6	_		0.4	_	0.4	
Input leakage cu	nput leakage current I <sub>IN</sub> V <sub>IN</sub> = 0~5.5 V		0~3.6	_	_	±0.1	_	±1.0	μΑ		
Power off leakage current I <sub>OFF</sub>		l <sub>OFF</sub>	V <sub>IN</sub> = 0~5.5 V V <sub>OUT</sub> = 0~3.6 V		0	_		1.0		10.0	μА
Quiescent supply current I <sub>CC</sub> \		$V_{IN} = V_{CC}$	V <sub>IN</sub> = V <sub>CC</sub> or GND		_	_	1.0	_	10.0	μΑ	

# AC Characteristics (Input: $t_r = t_f = 3 \text{ ns}$ )

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40~85°C		Unit	
Characteristics	Syllibol	rest Condition	V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	Offic
		C <sub>L</sub> = 10 pF,	0.9	_	19.8	_	_	_	
			1.1~1.3	_	10.1	18.7	1.0	34.5	
			1.4~1.6	_	5.9	8.9	1.0	10.8	
		$R_L = 1 M\Omega$	1.65~ 1.95	_	4.5	6.4	1.0	6.9	
			2.3~2.7	_	3.1	4.2	1.0	4.7	
			3.0~3.6	_	2.3	3.4	1.0	4.0	
	<sup>t</sup> pLH <sup>t</sup> pHL	$C_L = 15 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9	_	22.5	_	_	_	
			1.1~1.3	_	11.6	21.5	1.0	37.2	ns
Propagation delay time			1.4~1.6	_	6.6	9.8	1.0	12.0	
Propagation delay time			1.65~ 1.95	1	5.0	7.1	1.0	7.3	
			2.3~2.7	1	3.5	4.5	1.0	5.1	
			3.0~3.6	1	2.8	3.8	1.0	4.4	
		$C_L = 30 \ pF,$ $R_L = 1 \ M\Omega$	0.9	_	30.0	_	_	_	
			1.1~1.3	_	15.0	29.6	1.0	56.0	
			1.4~1.6	_	8.5	13.1	1.0	15.9	
			1.65~ 1.95	_	6.3	9.2	1.0	9.6	
			2.3~2.7		4.3	5.7	1.0	6.1	
			3.0~3.6		3.5	4.4	1.0	4.8	
Input capacitance	C <sub>IN</sub>	_	3.6	_	3	_	_	_	pF
Power dissipation capacitance	C <sub>PD</sub>	(Note13)	0.9 ~ 3.6		11	_	_		pF

Note 13: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

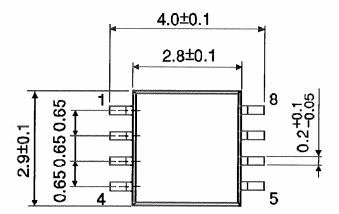
Average operating current can be obtained by the equation:

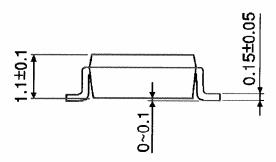
 $I_{CC \text{ (opr.)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$ 

# **Package Dimensions**

**TOSHIBA** 

SSOP8-P-0.65 Unit: mm



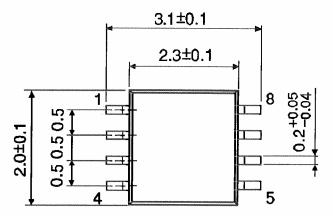


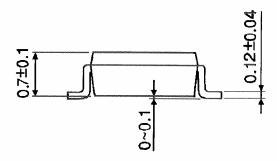
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Weight: 0.02 g (typ.)

# **Package Dimensions**

SSOP8-P-0.50A Unit: mm





6

Weight: 0.01 g (typ.)

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20070701-EN GENERAL

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